Triple low-ohmic single-pole double-throw analog switchRev. 5.1 — 30 March 2021Product data sheet

## **1** General description

The NX3L4053 is a triple low-ohmic single-pole double-throw analog switch, suitable for use as an analog or digital multiplexer/demultiplexer. Each switch has a digital select input (nS), two independent inputs/outputs (nY0 and nY1) and a common input/output (nZ). All three switches share an enable input ( $\overline{E}$ ). A digital enable pin  $\overline{E}$  is common to all switches.When  $\overline{E}$  is HIGH, the switches are turned off.

Schmitt trigger action at the digital inputs makes the circuit tolerant to slower input rise and fall times. Low threshold digital inputs allows this device to be driven by 1.8 V logic levels in 3.3 V applications without significant increase in supply current I<sub>CC</sub>. This makes it possible for the NX3L4053 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation. The NX3L4053 allows signals with amplitude up to V<sub>CC</sub> to be transmitted from nZ to nY0 or nY1; or from nY0 or nY1 to nZ. Its low ON resistance (0.5  $\Omega$ ) and flatness (0.13  $\Omega$ ) ensures minimal attenuation and distortion of transmitted signals.

## 2 Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
  - 1.8  $\Omega$  (typical) at V<sub>CC</sub> = 1.4 V
  - 1.0  $\Omega$  (typical) at V<sub>CC</sub> = 1.65 V
  - 0.6  $\Omega$  (typical) at V<sub>CC</sub> = 2.3 V
  - 0.6  $\Omega$  (typical) at V<sub>CC</sub> = 2.7 V
  - 0.5  $\Omega$  (typical) at V<sub>CC</sub> = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 4000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM AEC-Q100-011 revision B exceeds 1000 V
  - IEC61000-4-2 contact discharge exceeds 6000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- 1.8 V control logic at V<sub>CC</sub> = 3.6 V
- · Control input accepts voltages above supply voltage
- Very low supply current, even when input is below  $\mathsf{V}_{\mathsf{CC}}$
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



#### **Applications** 3

- · Cell phone
- PDA
- · Portable media player
- · Analog multiplexing and demultiplexing
- · Digital multiplexing and demultiplexing
- · Signal gating

#### **Ordering information** 4

#### Table 1. Ordering information

Type number	Topside	Package						
	mark	Name	Description	Version				
NX3L4053PW	X3L4053	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1				
NX3L4053HR	M43	HXQFN16	plastic thermal enhanced extremely thin quad flat package; no leads; 16 terminals; body 3 × 3 × 0.5 mm	SOT1039-2				

## 4.1 Ordering options

### Table 2. Ordering options

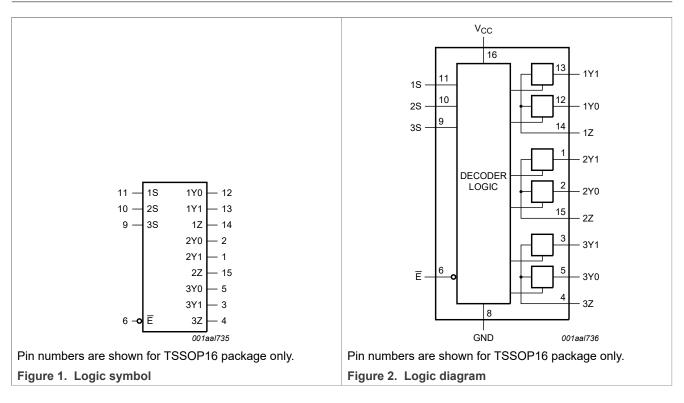
Type number	Orderable part number	Package	Packing method	Minimum order quantity	Temperature
NX3L4053PW	NX3L4053PW,118	TSSOP16	Reel 13" Q1/T1 NDP	2500	T <sub>amb</sub> = -40 °C to +125 °C
NX3L4053HR	NX3L4053HRZ	HXQFN16	Reel 7" Q1/T1 NDP SSB <sup>[1]</sup>	1500	$T_{amb}$ = -40 °C to +125 °C
	NX3L4053HR,115 <sup>[2]</sup>	HXQFN16	Reel 7" Q1/T1 NDP	1500	$T_{amb}$ = -40 °C to +125 °C

This packing method uses a Static Shielding Bag (SSB) solution. Material is to be kept in the sealed bag between uses. Will go EOL - migrate to new leadframe NX3L2467HRZ orderable part number. [1]

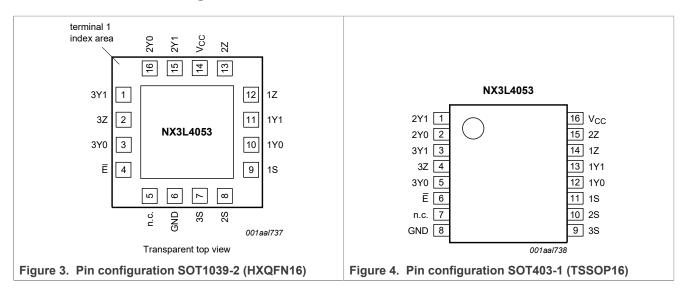
[2]

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## 5 Functional diagram



## 6 Pinning information



## 6.1 Pinning

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## 6.2 Pin description

#### Table 3. Pin description

Symbol	Pin	Pin				
	SOT1039-2	SOT403-1				
Ē	4	6	enable input (active LOW)			
n.c.	5	7	not connected			
GND	6	8	ground (0 V)			
1S, 2S, 3S	9, 8, 7	11, 10 ,9	select input			
1Y0, 2Y0, 3Y0	10, 16, 3	12, 2, 5	independent input or output			
1Y1, 2Y1, 3Y1	11, 15, 1	13, 1, 3	independent input or output			
1Z , 2Z, 3Z	12, 13, 2	14, 15, 4	independent output or input			
V <sub>CC</sub>	14	16	supply voltage			

## 7 Functional description

#### Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care.

Inputs		Channel on
E	nS	
L	L	nY0 to nZ
L	Н	nY1 to nZ
Н	X	switches off

## 8 Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+4.6	V
VI	input voltage	nS and Ē	[1]	-0.5	+4.6	V
V <sub>SW</sub>	switch voltage		[2]	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	input clamping current	V <sub>1</sub> < -0.5 V		-50	-	mA
I <sub>SK</sub>	switch clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V		-	±50	mA
I <sub>SW</sub>	switch current	witch current $V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V; source or sink current		-	±350	mA
		$V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current		-	±500	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C				1
		HXQFN16	[3]	-	250	mW

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#### Table 5. Limiting values...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Мах	Unit	
		TSSOP16	[4]	-	500	mW	

The minimum input voltage rating may be exceeded if the input current rating is observed. [1]

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] [4] For HXQFN16 package: above 135 °C the value of Ptot derates linearly with 16.9 mW/K.

For TSSOP16 package: above 60 °C the value of Ptot derates linearly with 5.5 mW/K.

#### **Recommended operating conditions** 9

#### Table 6. Recommended operating conditions

Symbol	Parameter	Conditions		Min	Мах	Unit
V <sub>CC</sub>	supply voltage			1.4	4.3	V
VI	input voltage	nS and E		0	4.3	V
V <sub>SW</sub>	switch voltage		[1]	0	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature			-40	+125	°C
Δt/ΔV	input transition rise and fall rate	nS and $\overline{E}$ ; V <sub>CC</sub> = 1.4 V to 4.3 V		-	200	ns/V

To avoid sinking GND current from terminal nZ when switch current flows in terminal nYn, the voltage drop across the bidirectional switch must not exceed [1] 0.4 V. If the switch current flows into terminal nZ, no GND current will flow from terminal nYn. In this case, there is no limit for the voltage drop across the switch.

## 10 Static characteristics

#### Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Ta	T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +125 °C			
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)		
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 1.4 V to 1.6 V	0.9	-	-	0.9	-	-	V	
	input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	0.9	-	-	0.9	-	-	V	
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V	
		V <sub>CC</sub> = 2.7 V to 3.6 V	1.3	-	-	1.3	-	-	V	
		V <sub>CC</sub> = 3.6 V to 4.3 V	1.4	-	-	1.4	-	-	V	
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 1.4 V to 1.6 V	-	-	0.3	-	0.3	0.3	V	
	input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V	
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.4	-	0.4	0.4	V	
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.5	-	0.5	0.5	V	
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	-	0.6	-	0.6	0.6	V	
l <sub>l</sub>	input leakage current	nS and E; V <sub>I</sub> = GND to 4.3 V; V <sub>CC</sub> = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μA	

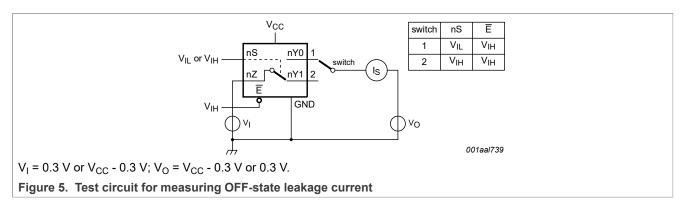
#### Triple low-ohmic single-pole double-throw analog switch

### Table 7. Static characteristics...continued

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Т	<sub>amb</sub> = 25	°C	T <sub>amb</sub> = -40 °C to +125 °C			
			Min	Тур	Мах	Min	Max (85 °C)	Max (125 °C)	-
I <sub>S(OFF)</sub>	(OFF) OFF-state leakage current	nY0 and nY1 port; see <u>Figure 5</u>							
		V <sub>CC</sub> = 1.4 V to 3.6 V	-	-	±5	-	±50	±500	nA
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	-	±10	-	±50	±500	nA
leaka	ON-state leakage	nZ port; V <sub>CC</sub> = 1.4 V to 3.6 V; see <u>Figure 6</u>							
	current	V <sub>CC</sub> = 1.4 V to 3.6 V	-	-	±5	-	±50	±500	nA
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	-	±10	-	±50	±500	nA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $V_{SW} =$ GND or $V_{CC}$							
		V <sub>CC</sub> = 3.6 V	-	-	100	-	500	5000	nA
		V <sub>CC</sub> = 4.3 V	-	-	150	-	800	6000	nA
ΔI <sub>CC</sub>	additional	V <sub>SW</sub> = GND or V <sub>CC</sub>							
	supply current	V <sub>I</sub> = 2.6 V; V <sub>CC</sub> = 4.3 V	-	2.0	4.0	-	7	7	μA
		V <sub>I</sub> = 2.6 V; V <sub>CC</sub> = 3.6 V	-	0.35	0.7	-	1	1	μA
		V <sub>I</sub> = 1.8 V; V <sub>CC</sub> = 4.3 V	-	7.0	10.0	-	15	15	μA
		V <sub>I</sub> = 1.8 V; V <sub>CC</sub> = 3.6 V	-	2.5	4.0	-	5	5	μA
		V <sub>I</sub> = 1.8 V; V <sub>CC</sub> = 2.5 V	-	50	200	-	300	500	nA
CI	input capacitance	nS and E	-	1.0	-	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance		-	35	-	-	-	-	pF
C <sub>S(ON)</sub>	ON-state capacitance		-	130	-	-	-	-	pF

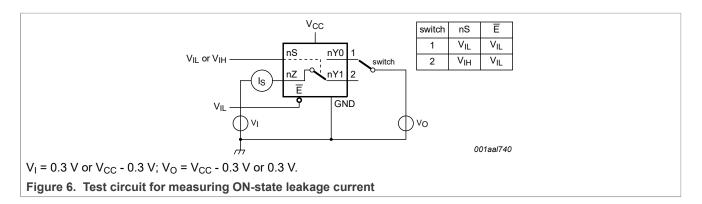
## 10.1 Test circuits



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### 10.2 ON resistance

### Table 8. ON resistance<sup>[1]</sup>

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 8 to Figure 14.

Symbol	Parameter	Conditions		T <sub>amb</sub> =	= -40 °C to	• +85 °C	T <sub>amb</sub> = -40 °	Unit	
				Min	Typ <sup>[2]</sup>	Мах	Min	Max	-
R <sub>ON(peak)</sub>	ON resistance (peak)	$V_{I}$ = GND to $V_{CC}$ ; $I_{SW}$ = 100 mA; see <u>Figure 7</u>							
		V <sub>CC</sub> = 1.4 V		-	1.8	3.8	-	4.2	Ω
		V <sub>CC</sub> = 1.65 V		-	1.0	1.7	-	1.8	Ω
		V <sub>CC</sub> = 2.3 V		-	0.6	0.9	-	1.0	Ω
	V <sub>CC</sub> = 2.7 V		-	0.6	0.80	-	1.0	Ω	
		V <sub>CC</sub> = 4.3 V		-	0.5	0.80	-	1.0	Ω
ΔR <sub>ON</sub>	ON resistance mismatch	$V_I = GND$ to $V_{CC}$ ; $I_{SW} =$ 100 mA	[3]						
	between channels	$V_{CC}$ = 1.4 V; $V_{SW}$ = 0.4 V		-	0.23	0.38	-	0.38	Ω
		V <sub>CC</sub> = 1.65 V; V <sub>SW</sub> = 0.5 V		-	0.23	0.28	-	0.38	Ω
		V <sub>CC</sub> = 2.3 V; V <sub>SW</sub> = 0.7 V		-	0.12	0.15	-	0.18	Ω
		V <sub>CC</sub> = 2.7 V; V <sub>SW</sub> = 0.8 V		-	0.12	0.15	-	0.18	Ω
		V <sub>CC</sub> = 4.3 V; V <sub>SW</sub> = 0.8 V		-	0.12	0.15	-	0.18	Ω
R <sub>ON(flat)</sub>	ON resistance (flatness)	$V_I = GND$ to $V_{CC}$ ; $I_{SW} =$ 100 mA	[4]						
		V <sub>CC</sub> = 1.4 V		-	1.0	3.3	-	3.6	Ω
		V <sub>CC</sub> = 1.65 V		-	0.5	1.2	-	1.3	Ω
		V <sub>CC</sub> = 2.3 V		-	0.15	0.3	-	0.35	Ω
		V <sub>CC</sub> = 2.7 V		-	0.13	0.3	-	0.35	Ω
		V <sub>CC</sub> = 4.3 V		-	0.2	0.4	-	0.45	Ω

For NX3L4053PW (TSSOP16 package), all ON resistance values are up to  $0.05 \Omega$  higher. [1]

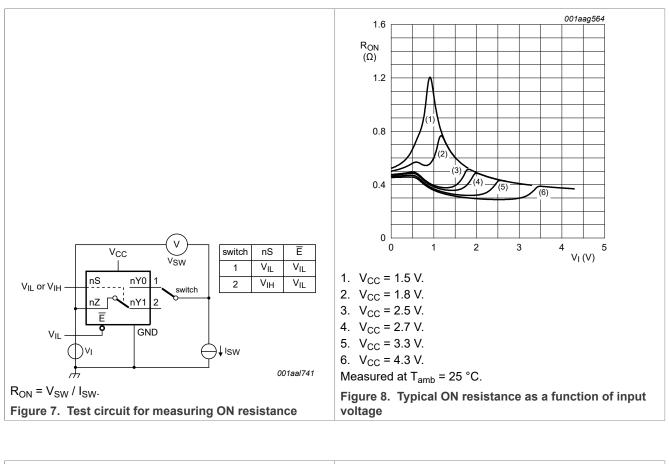
[2] [3]

Typical values are measured at  $T_{amb} = 25$  °C. Measured at identical  $V_{CC}$ , temperature and input voltage. Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical  $V_{CC}$  and temperature. [4]

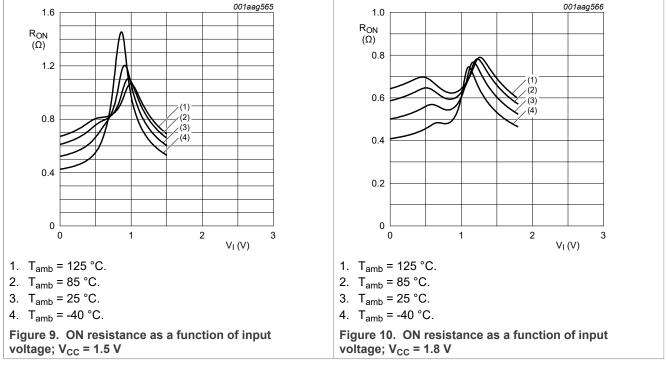
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### 10.3 ON resistance test circuit and graphs



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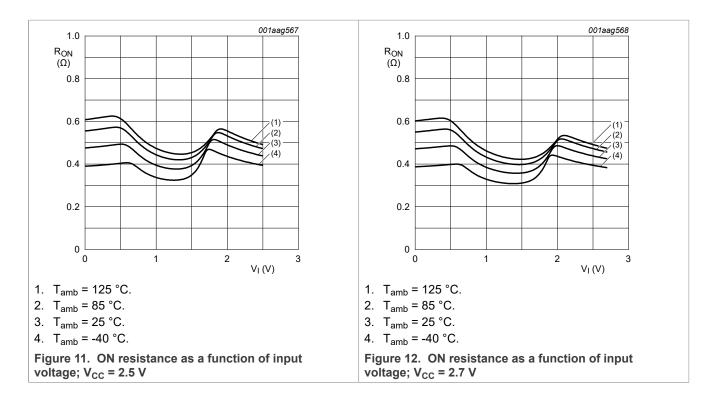
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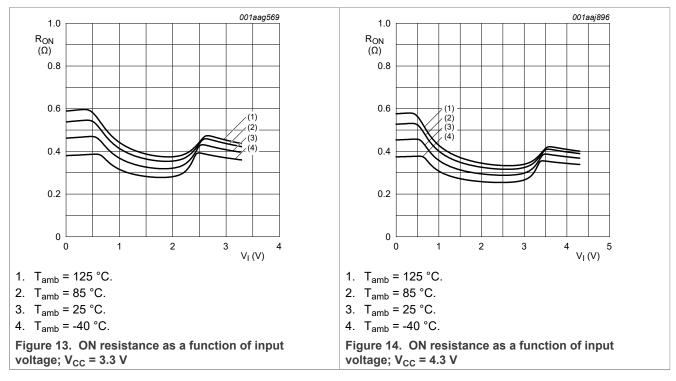
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#### Triple low-ohmic single-pole double-throw analog switch





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## **11 Dynamic characteristics**

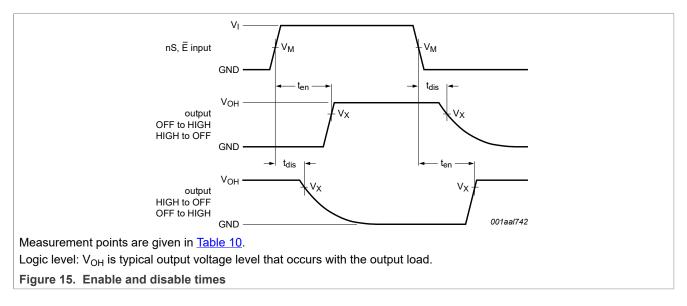
#### Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

Symbol	Parameter	Conditions		Ta	<sub>mb</sub> = 25	°C	T <sub>amb</sub> =	-40 °C to	+125 °C	Unit
				Min	Typ <sup>[1]</sup>	Мах	Min	Max (85 °C)	Max (125 °C)	
t <sub>en</sub>	enable time	Ē, nS to nZ or nYn; see Figure 15								
		V <sub>CC</sub> = 1.4 V to 1.6 V		-	49	90	-	120	120	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		-	35	70	-	80	90	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V		-	23	45	-	50	55	ns
		V <sub>CC</sub> = 2.7 V to 3.6 V		-	21	40	-	45	50	ns
		V <sub>CC</sub> = 3.6 V to 4.3 V		-	21	40	-	45	50	ns
t <sub>dis</sub>	disable time	Ē, nS to nZ or nYn; see Figure 15								
		V <sub>CC</sub> = 1.4 V to 1.6 V		-	32	70	-	80	90	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		-	17	55	-	60	65	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V		-	11	25	-	30	35	ns
		V <sub>CC</sub> = 2.7 V to 3.6 V		-	8	20	-	25	30	ns
		V <sub>CC</sub> = 3.6 V to 4.3 V		-	8	20	-	25	30	ns
t <sub>b-m</sub>	break-before-make	see Figure 16	[2]							
	time	V <sub>CC</sub> = 1.4 V to 1.6 V		-	19	-	9	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		-	17	-	7	-	-	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V		-	13	-	4	-	-	ns
		V <sub>CC</sub> = 2.7 V to 3.6 V		-	10	-	3	-	-	ns
		V <sub>CC</sub> = 3.6 V to 4.3 V		-	9	-	2	-	-	ns

Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively. Break-before-make guaranteed by design. [1] [2]

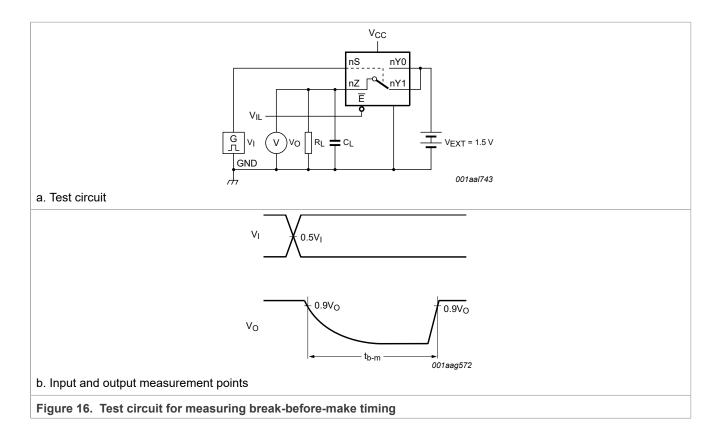
## 11.1 Waveform and test circuits

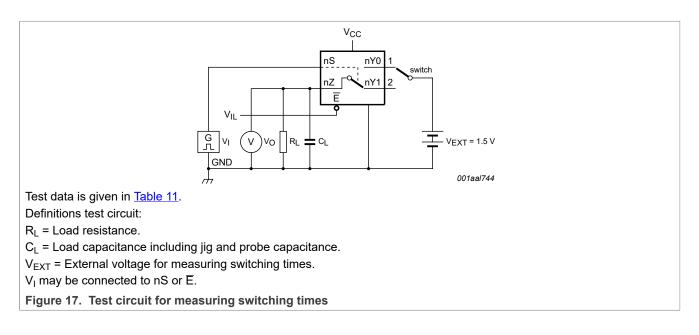


#### Table 10. Measurement points

Supply voltage	Input	Output
Vcc	V <sub>M</sub>	V <sub>X</sub>
1.4 V to 4.3 V	0.5V <sub>CC</sub>	0.9V <sub>OH</sub>

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#### Table 11. Test data

Supply voltage	Input Load			
V <sub>cc</sub>	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL
1.4 V to 4.3 V	V <sub>CC</sub>	≤ 2.5 ns	35 pF	50 Ω

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## 11.2 Additional dynamic characteristics

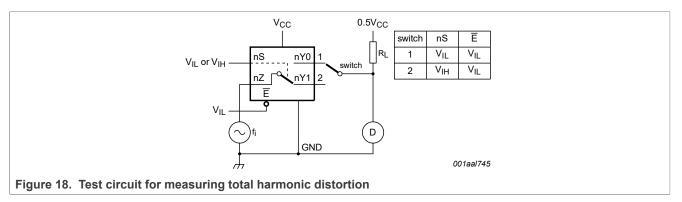
#### Table 12. Additional dynamic characteristics

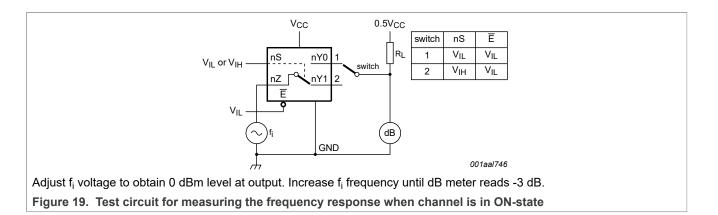
At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = GND$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \le 2.5$  ns;  $T_{amb} = 25$  °C.

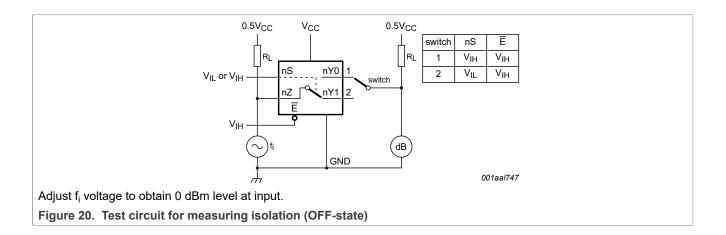
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
THD total ha	total harmonic	$f_i = 20$ Hz to 20 kHz; $R_L = 32 \Omega$ ; see Figure 18	[1]				
	distortion	V <sub>CC</sub> = 1.4 V; V <sub>I</sub> = 1 V (p-p)		-	0.15	-	%
		V <sub>CC</sub> = 1.65 V; V <sub>I</sub> = 1.2 V (p-p)		-	0.10	-	%
		V <sub>CC</sub> = 2.3 V; V <sub>I</sub> = 1.5 V (p-p)		-	0.02	-	%
		V <sub>CC</sub> = 2.7 V; V <sub>I</sub> = 2 V (p-p)		-	0.02	-	%
		V <sub>CC</sub> = 4.3 V; V <sub>I</sub> = 2 V (p-p)		-	0.02	-	%
f <sub>(-3dB)</sub>	-3 dB frequency	$R_L$ = 50 Ω; see Figure 19	[1]				
	response	V <sub>CC</sub> = 1.4 V to 4.3 V		-	60	-	MHz
α <sub>iso</sub>	isolation (OFF-state)	$f_i$ = 100 kHz; R <sub>L</sub> = 50 Ω; see <u>Figure 20</u>	[1]				
		V <sub>CC</sub> = 1.4 V to 4.3 V		-	-90	-	dB
V <sub>ct</sub> crosstalk voltage	crosstalk voltage	between digital inputs and switch; f <sub>i</sub> = 1 MHz; C <sub>L</sub> = 50 pF; R <sub>L</sub> = 50 $\Omega$ ; see Figure 21					
		V <sub>CC</sub> = 1.4 V to 3.6 V		-	0.2	-	V
		V <sub>CC</sub> = 3.6 V to 4.3 V		-	0.3	-	V
Xtalk	crosstalk	between switches; f <sub>i</sub> = 100 kHz; R <sub>L</sub> = 50 $\Omega$ ; see Figure 22	[1]				
		V <sub>CC</sub> = 1.4 V to 4.3 V		-	-90	-	dB
Q <sub>inj</sub> charge injection	charge injection	$f_i$ = 1 MHz; C <sub>L</sub> = 0.1 nF; R <sub>L</sub> = 1 MΩ; V <sub>gen</sub> = 0 V; R <sub>gen</sub> = 0 Ω; see Figure 23					
		V <sub>CC</sub> = 1.5 V		-	3	-	рС
		V <sub>CC</sub> = 1.8 V		-	4	-	рС
		V <sub>CC</sub> = 2.5 V		-	6	-	рС
		V <sub>CC</sub> = 3.3 V		-	9	-	рС
		V <sub>CC</sub> = 4.3 V		-	15	-	рС

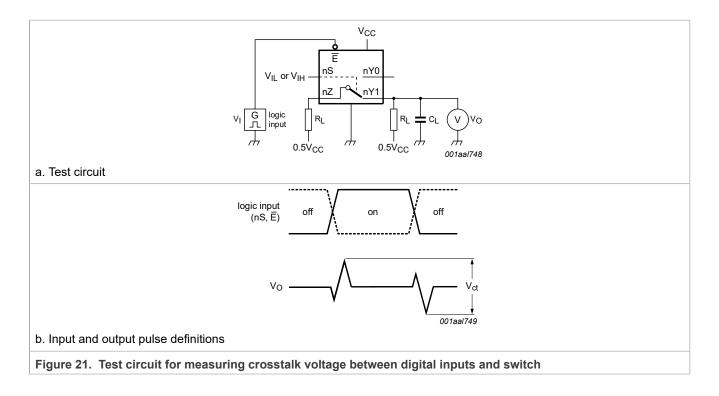
[1] f<sub>i</sub> is biased at 0.5V<sub>CC</sub>.

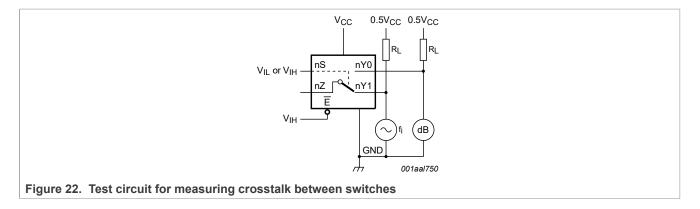
## 11.3 Test circuits



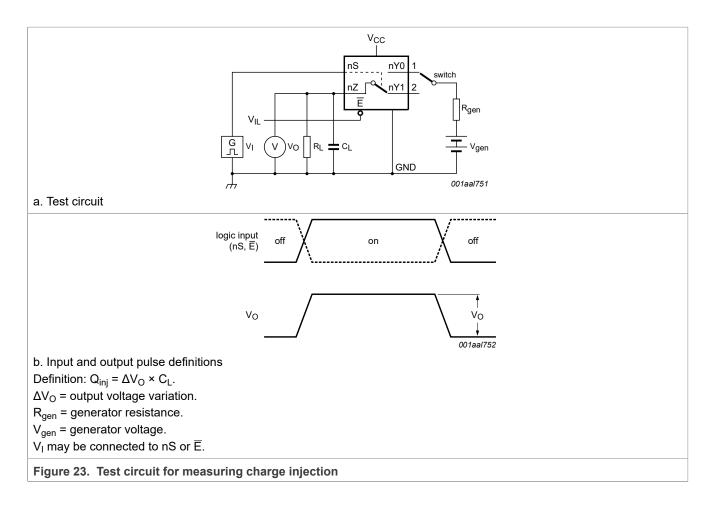






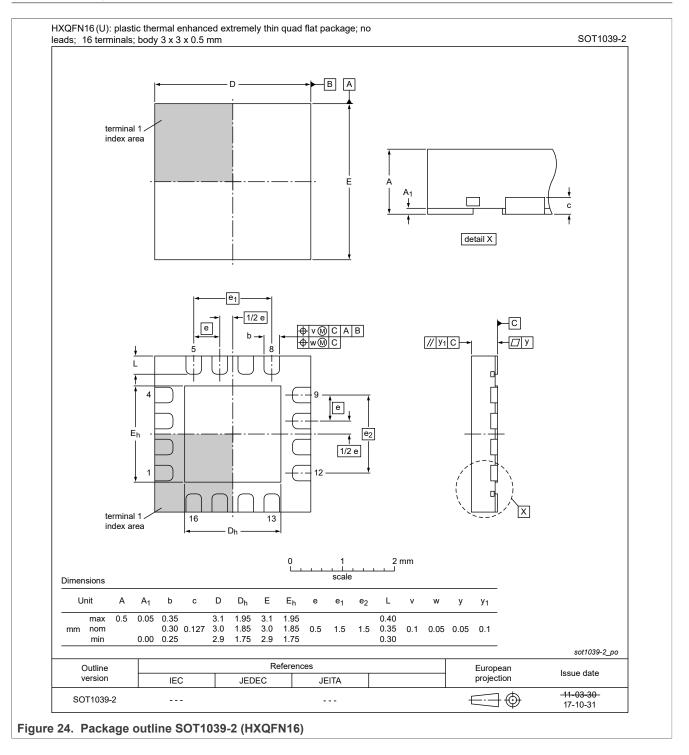


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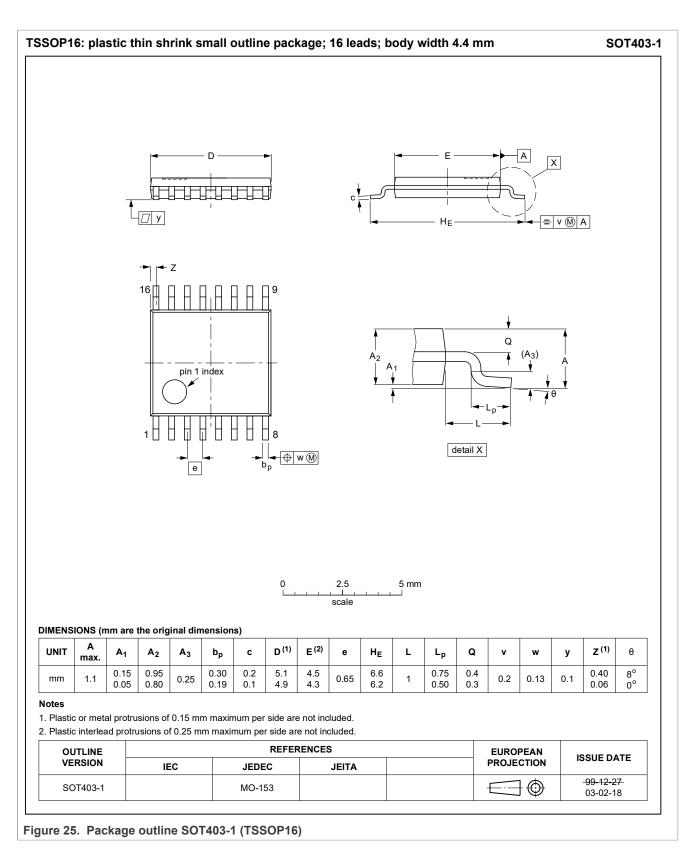
## 12 Package outline



## **NXP Semiconductors**

## NX3L4053

### Triple low-ohmic single-pole double-throw analog switch



NX3L4053

## **13 Abbreviations**

Table 13. Abbreviations				
Acronym	Description			
CDM	Charged Device Model			
CMOS	Complementary Metal-Oxide Semiconductor			
ESD	ElectroStatic Discharge			
НВМ	Human Body Model			
ММ	Machine Model			
PDA	Personal Digital Assistant			

## 14 Revision history

### Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L4053 v.5.1	20210330	Product data sheet	-	NX3L4053 v.5
Modifications:	Updated <u>Sec</u>	tion 4 "Ordering information"	•	
NX3L4053 v.5	20120625	Product data sheet	-	NX3L4053 v.4
NX3L4053 v.4	20111107	Product data sheet	-	NX3L4053 v.3
Modifications:	<ul> <li>Legal pages</li> </ul>	updated.		1
NX3L4053 v.3	20101223	Product data sheet	-	NX3L4053 v.2
NX3L4053 v.2	20100811	Product data sheet	-	NX3L4053 v.1
NX3L4053 v.1	20100416	Product data sheet	-	-

## **15** Legal information

### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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